

DATA SHEET

74ALVCH16843

18-bit bus-interface D-type latch (3-State)

Product specification

1998 Aug 04

IC24 Data Handbook



18-bit bus interface D-type latch (3-State)

74ALVCH16843

FEATURES

- Wide supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A.
- CMOS low power consumption
- Direct interface with TTL levels
- Current drive ± 24 mA at 3.0 V
- MULTIBYTE™ flow-through standard pin-out architecture
- Low inductance multiple V_{CC} and GND pins for minimum noise and ground bounce
- All data inputs have bus hold
- Output drive capability 50 Ω transmission lines @ 85°C

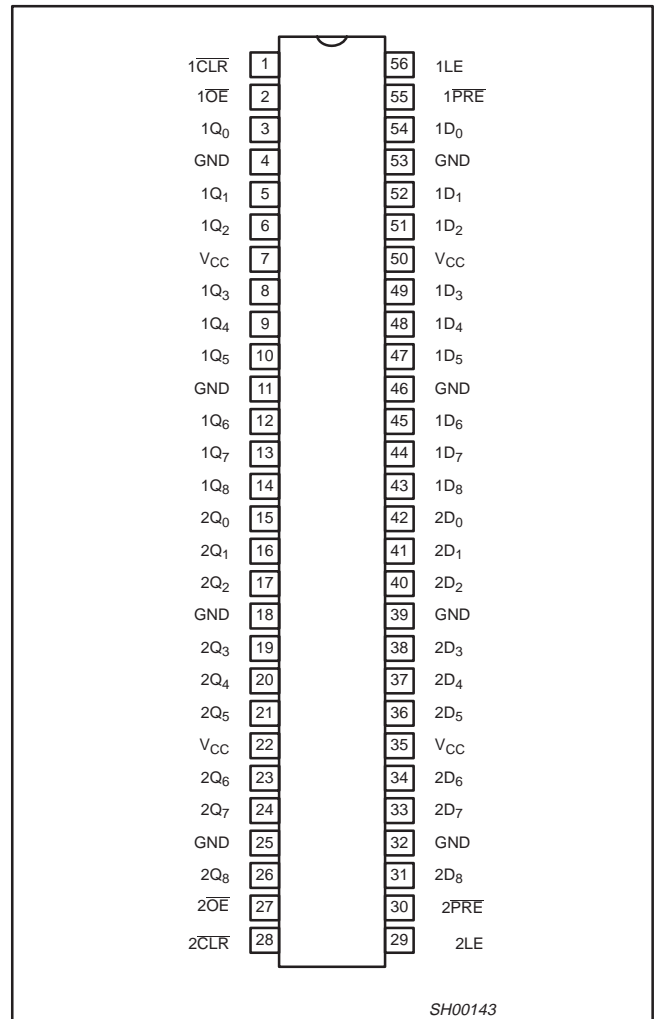
DESCRIPTION

The 74ALVCH16843 has two 9-bit D-type latch featuring separate D-type inputs for each latch and 3-State outputs for bus oriented applications. The two sections of each register are controlled independently by the latch enable (nLE), clear (nCLR), preset (nPRE) and output enable (nOE) control gates.

When nOE is LOW, the data in the registers appear at the outputs. When nOE is HIGH, the outputs are in the high impedance OFF state. Operation of the nOE input does not affect the state of the flip-flops.

The 74ALVCH16843 has active bus hold circuitry which is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.

PIN CONFIGURATION



QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}\text{C}$; $t_r = t_f \leq 2.5\text{ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT	
t_{PHL}/t_{PLH}	Propagation delay nDn to nQn	$V_{CC} = 2.5\text{V}, C_L = 30\text{pF}$ $V_{CC} = 3.3\text{V}, C_L = 50\text{pF}$	2.2 2.1	ns	
	Propagation delay nLE to nQn	$V_{CC} = 2.5\text{V}, C_L = 30\text{pF}$ $V_{CC} = 3.3\text{V}, C_L = 50\text{pF}$	2.3 2.0	ns	
C_I	Input capacitance		5.0	pF	
C_{PD}	Power dissipation capacitance per buffer	$V_I = \text{GND to } V_{CC}^1$	transparent mode Output enabled Output disabled	17 3	pF
			Clocked mode Output enabled Output disabled	19 9	

NOTES:

- C_{PD} is used to determine the dynamic power dissipation (P_D in μW):
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; C_L = output load capacitance in pF;
 f_o = output frequency in MHz; V_{CC} = supply voltage in V; $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DRAWING NUMBER
56-Pin Plastic Thin Shrink Small Outline (TSSOP) Type II	$-40^{\circ}\text{C to } +85^{\circ}\text{C}$	74ALVCH16843 DGG	ACH16843 DGG	SOT364-1

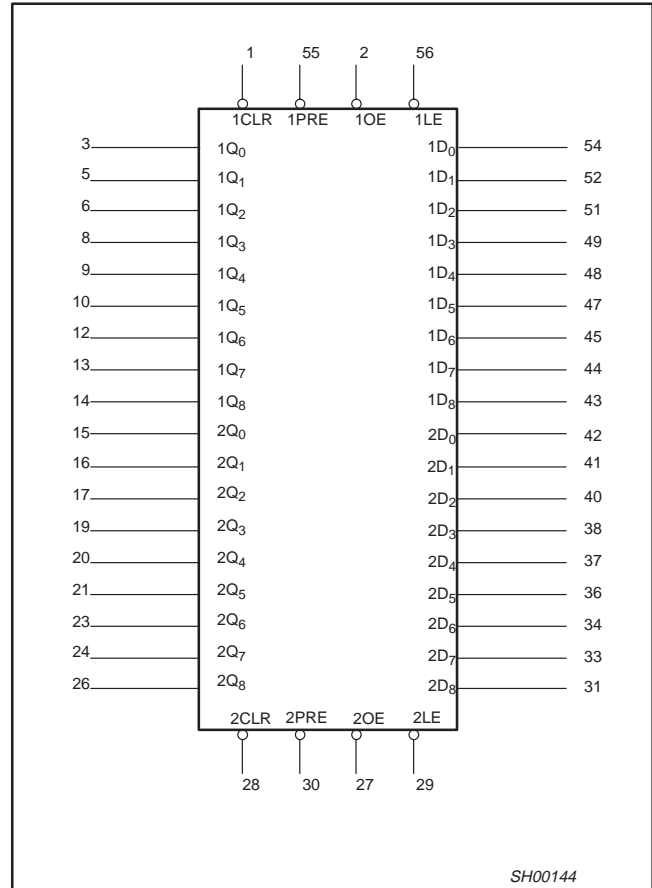
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PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	1CLR	Clear input (active LOW)
2	1OE	Output enable input (active LOW)
55	1PRE	Preset input (active LOW)
56	1LE	Latch enable input (active HIGH)
54, 52, 51, 49, 48, 47, 45, 44, 43	1D0 to 1D8	Data inputs
3, 5, 6, 8, 9, 10, 12, 13, 14	1Q0 to 1Q8	Data outputs
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage
27	2OE	Output enable input (active LOW)
28	2CLR	Clear input (active LOW)
29	2LE	Latch enable input (active HIGH)
30	2PRE	Preset input (active LOW)
42, 41, 40, 38, 37, 36, 34, 33, 31	2D0 to 2D8	Data inputs
15, 16, 17, 19, 20, 21, 23, 24, 26	2Q0 to 2Q8	Data outputs

LOGIC SYMBOL



FUNCTION TABLE

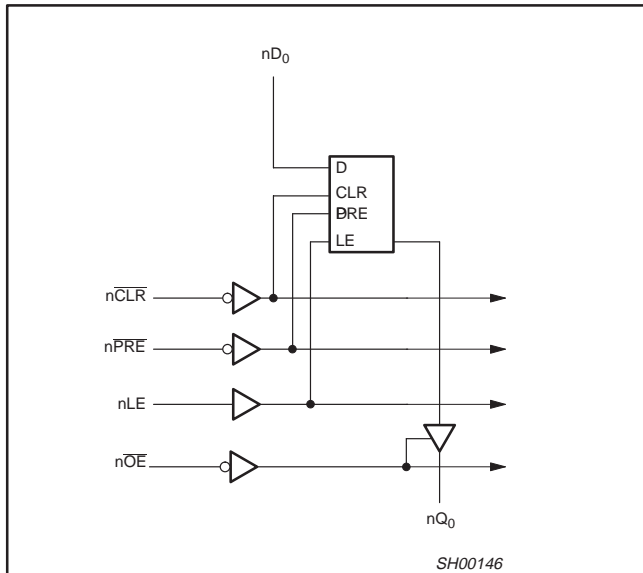
INPUTS					OUTPUT
nPRE	nCLR	nOE	LE	D _x	Q
L	X	L	X	X	H
H	L	L	X	X	L
H	H	L	H	L	L
H	H	L	H	H	H
H	H	L	H	X	Q ₀
X	X	H	H	X	Z

- H = HIGH voltage level
- L = LOW voltage level
- X = Don't care
- Z = High impedance "off" state

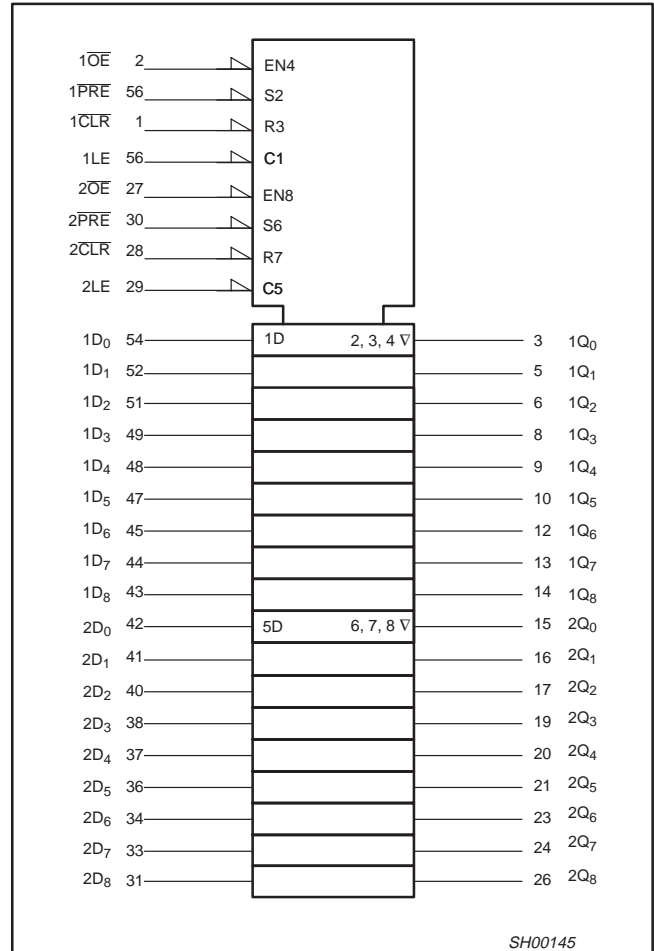
18-bit bus interface D-type latch (3-State)

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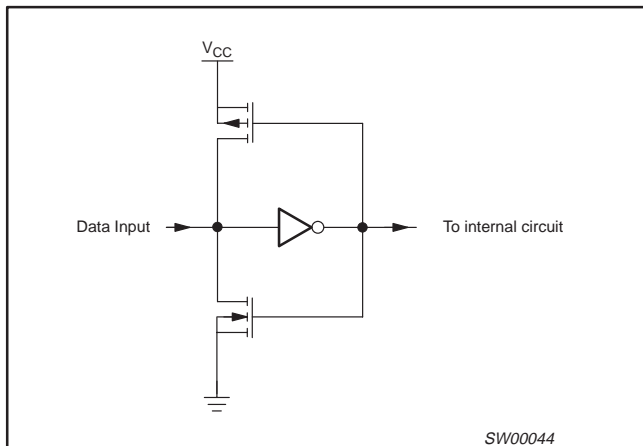
LOGIC DIAGRAM



LOGIC SYMBOL (IEEE/IEC)



BUS HOLD CIRCUIT



18-bit bus interface D-type latch (3-State)

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V_{CC}	DC supply voltage 2.5V range (for max. speed performance @ 30 pF output load)		2.3	2.7	V
	DC supply voltage 3.3V range (for max. speed performance @ 50 pF output load)		3.0	3.6	
V_I	DC Input voltage range		0	V_{CC}	V
V_O	DC output voltage range		0	V_{CC}	V
T_{amb}	Operating free-air temperature range		-40	+85	°C
t_r, t_f	Input rise and fall times	$V_{CC} = 2.3$ to $3.0V$ $V_{CC} = 3.0$ to $3.6V$	0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS

In accordance with the Absolute Maximum Rating System (IEC 134)

Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to +4.6	V
I_{IK}	DC input diode current	$V_I < 0$	-50	mA
V_I	DC input voltage	For control pins ²	-0.5 to +4.6	V
		For data inputs ²	-0.5 to $V_{CC} + 0.5$	
I_{OK}	DC output diode current	$V_O > V_{CC}$ or $V_O < 0$	± 50	mA
V_O	DC output voltage	Note 2	-0.5 to $V_{CC} + 0.5$	V
I_O	DC output source or sink current	$V_O = 0$ to V_{CC}	± 50	mA
I_{GND}, I_{CC}	DC V_{CC} or GND current		± 100	mA
T_{stg}	Storage temperature range		-65 to +150	°C
P_{TOT}	Power dissipation per package	For temperature range: -40 to +125 °C above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	850 600	mW
	-plastic medium-shrink (SSOP) -plastic thin-medium-shrink (TSSOP)			

NOTE:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Temp = -40°C to +85°C			
			MIN	TYP ¹	MAX	
V _{IH}	HIGH level Input voltage	V _{CC} = 2.3 to 2.7V	1.7	1.2		V
		V _{CC} = 2.7 to 3.6V	2.0	1.5		
V _{IL}	LOW level Input voltage	V _{CC} = 2.3 to 2.7V		1.2	0.7	V
		V _{CC} = 2.7 to 3.6V		1.5	0.8	
V _{OH}	HIGH level output voltage	V _{CC} = 2.3 to 3.6V; V _I = V _{IH} or V _{IL} ; I _O = -100μA	V _{CC} - 0.2	V _{CC}		V
		V _{CC} = 2.3V; V _I = V _{IH} or V _{IL} ; I _O = -6mA	V _{CC} - 0.3	V _{CC} - 0.08		
		V _{CC} = 2.3V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.6	V _{CC} - 0.26		
		V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.5	V _{CC} - 0.14		
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.6	V _{CC} - 0.09		
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -24mA	V _{CC} - 1.0	V _{CC} - 0.28		
V _{OL}	LOW level output voltage	V _{CC} = 2.3 to 3.6V; V _I = V _{IH} or V _{IL} ; I _O = 100μA		GND	0.20	V
		V _{CC} = 2.3V; V _I = V _{IH} or V _{IL} ; I _O = 6mA		0.07	0.40	V
		V _{CC} = 2.3V; V _I = V _{IH} or V _{IL} ; I _O = 12mA		0.15	0.70	V
		V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = 12mA		0.14	0.40	
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 24mA		0.27	0.55	
I _I	Input leakage current	V _{CC} = 2.3 to 3.6V; V _I = V _{CC} or GND		0.1	5	μA
I _{OZ}	3-State output OFF-state current	V _{CC} = 2.3 to 3.6V; V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND		0.1	10	μA
I _{CC}	Quiescent supply current	V _{CC} = 2.3 to 3.6V; V _I = V _{CC} or GND; I _O = 0		0.2	40	μA
ΔI _{CC}	Additional quiescent supply current	V _{CC} = 2.3V to 3.6V; V _I = V _{CC} - 0.6V; I _O = 0		150	750	μA
I _{BHL} ²	Bus hold LOW sustaining current	V _{CC} = 2.3V; V _I = 0.7V	45	-		μA
		V _{CC} = 3.0V; V _I = 0.8V	75	150		
I _{BHH} ²	Bus hold HIGH sustaining current	V _{CC} = 2.3V; V _I = 1.7V	-45			μA
		V _{CC} = 3.0V; V _I = 2.0V	-75	-175		
I _{BHLO} ²	Bus hold LOW overdrive current	V _{CC} = 3.6V	500			μA
I _{BHHO} ²	Bus hold HIGH overdrive current	V _{CC} = 3.6V	-500			μA

NOTES:

1. All typical values are at T_{amb} = 25°C.
2. Valid for data inputs of bus hold parts.

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AC CHARACTERISTICS FOR $V_{CC} = 2.3V$ TO $2.7V$ RANGEGND = 0V; $t_r = t_f \leq 2.0ns$; $C_L = 30pF$

SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT
			$V_{CC} = 2.3$ to $2.7V$			
			MIN	TYP ¹	MAX	
t_{PHL}/t_{PLH}	Propagation delay nDn to nQn	1, 6	1.0	2.2	4.3	ns
	Propagation delay nLE to nQn	2, 6	1.0	2.3	4.6	
	Propagation delay nPRE to nQn	1, 6	1.0	2.5	4.8	
	Propagation delay nCLR to nQn	1, 6	1.0	2.5	4.8	
t_{PZH}/t_{PZL}	3-State output enable time nOE to nQn	5, 6	1.0	2.8	5.8	ns
t_{PHZ}/t_{PLZ}	3-State output disable time nOE to nQn	5, 6	1.1	2.2	4.3	ns
t_{SU}	Set-up time nDn to nLE	3, 6	0.5	-0.1	-	ns
t_h	Hold time nDn to nLE	3, 6	0.9	0.5	-	ns
t_w	nLE pulse width HIGH	2, 6	1.5	0.5	-	ns
	nPRE pulse width LOW	4, 6	1.5	0.5	-	
	nCLR pulse width LOW	4, 6	1.5	0.5	-	
t_{REM}	Recovery time nPRE to nLE	4, 6	0.5	1.1	-	ns
	Recovery time nCLR to nLE	4, 6	0.5	1.0	-	

NOTE:1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^\circ C$.**AC CHARACTERISTICS FOR $V_{CC} = 3.0V$ TO $3.6V$ RANGE AND $V_{CC} = 2.7V$** GND = 0V; $t_r = t_f \leq 2.5ns$; $C_L = 50pF$

SYMBOL	PARAMETER	WAVEFORM	LIMITS			LIMITS			UNIT
			$V_{CC} = 3.3 \pm 0.3V$			$V_{CC} = 2.7V$			
			MIN	TYP ^{1, 2}	MAX	MIN	TYP ¹	MAX	
t_{PHL}/t_{PLH}	Propagation delay nDn to nQn	1, 6	1.0	2.1	3.5	1.0	2.3	4.0	ns
	Propagation delay nLE to nQn	2, 6	1.0	2.0	3.5	1.0	2.1	3.9	
	Propagation delay nPRE to nQn	1, 6	1.0	2.2	3.8	1.0	2.6	4.5	
	Propagation delay nCLR to nQn	1, 6	1.0	2.3	3.9	1.0	2.5	4.3	
t_{PZH}/t_{PZL}	3-State output enable time nOE to nQn	5, 6	1.0	2.5	4.4	1.0	3.0	5.3	ns
t_{PHZ}/t_{PLZ}	3-State output disable time nOE to nQn	5, 6	1.3	2.6	4.0	1.3	2.8	4.4	ns
t_{SU}	Set-up time nDn to nLE	3, 6	0.5	0.0	-	0.5	-0.3	-	ns
t_h	Hold time nDn to nLE	3, 6	0.9	0.5	-	0.9	0.5	-	ns
t_w	nLE pulse width HIGH	2, 6	1.5	0.5	-	1.5	0.5	-	ns
	nPRE pulse width LOW	4, 6	1.5	0.5	-	1.5	0.6	-	
	nCLR pulse width LOW	4, 6	1.5	0.5	-	1.5	0.5	-	
t_{REM}	Recovery time nPRE to nLE	4, 6	1.0	0.4	-	0.8	-0.2	-	ns
	Recovery time nCLR to nLE	4, 6	0.8	0.2	-	0.6	-0.4	-	

NOTES:

- All typical values are measured $T_{amb} = 25^\circ C$.
- Typical value is measured at $V_{CC} = 3.3V$

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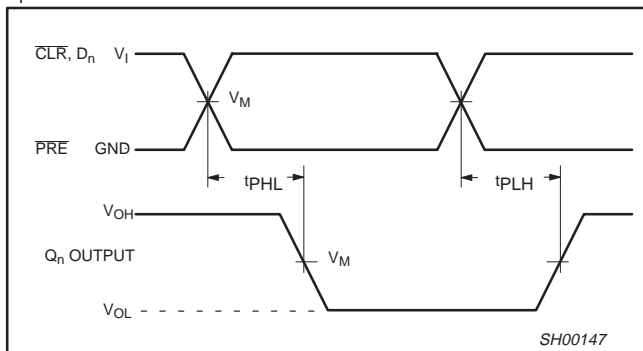
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AC WAVEFORMS FOR $V_{CC} = 2.3V$ TO $2.7V$ AND $V_{CC} < 2.3V$ RANGE

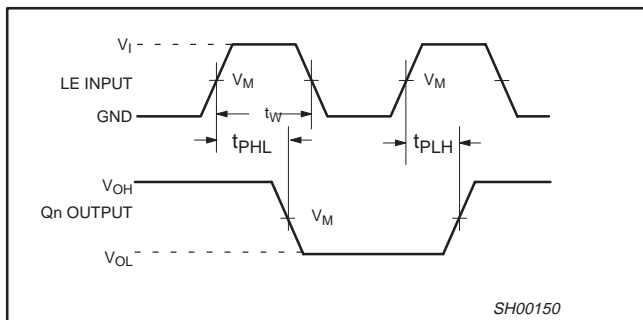
$V_M = 0.5 V$
 $V_X = V_{OL} + 0.15V$
 $V_Y = V_{OH} - 0.15V$
 V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.
 $V_I = V_{CC}$

AC WAVEFORMS FOR $V_{CC} = 3.0V$ TO $3.6V$ AND $V_{CC} = 2.7V$ RANGE

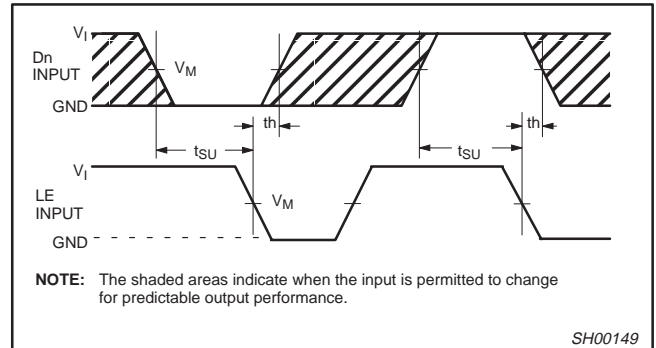
$V_M = 1.5 V$
 $V_X = V_{OL} + 0.3V$
 $V_Y = V_{OH} - 0.3V$
 V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.
 $V_I = 2.7V$



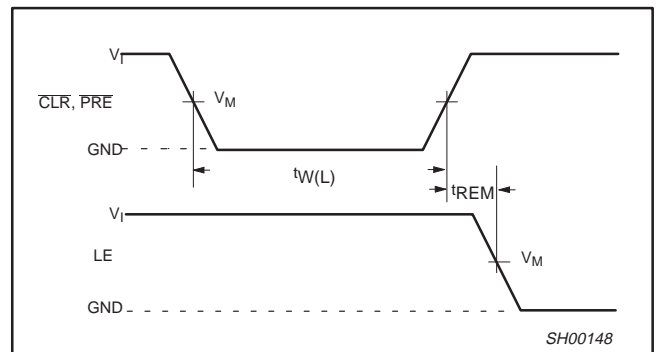
Waveform 1. Data input (Dn) to output (Qn), clear input (CLR) to output (Qn) and preset input (PRE) to output (Qn) propagation delay



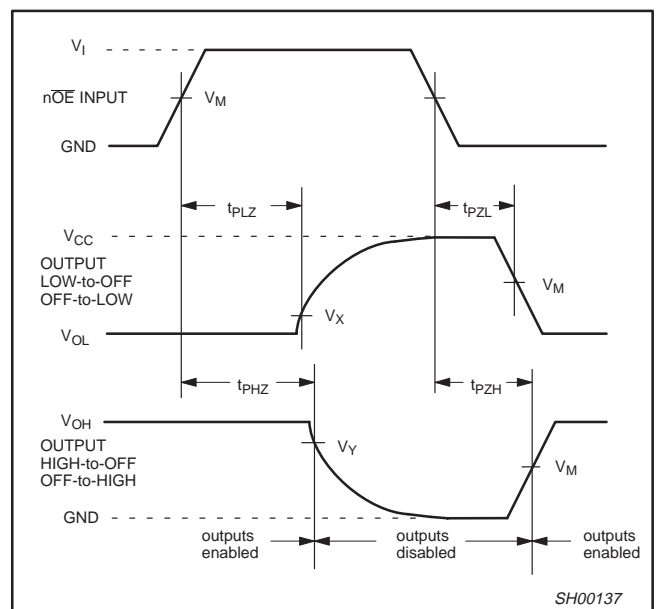
Waveform 2. Latch enable input (LE) pulse width, the latch enable input to output (Qn) propagation delay



Waveform 3. Data set-up and hold times for the Dn input to the LE input



Waveform 4. Clear (CLR) and preset (PRE) pulse width, the clear (CLR) and preset (PRE) to latch (LE) removal time

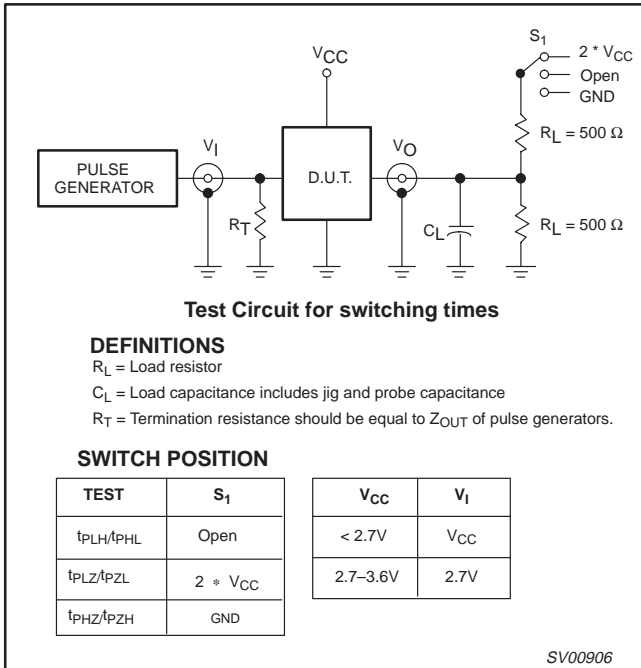


Waveform 5. 3-State enable and disable times

18-bit bus interface D-type latch (3-State)

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TEST CIRCUIT



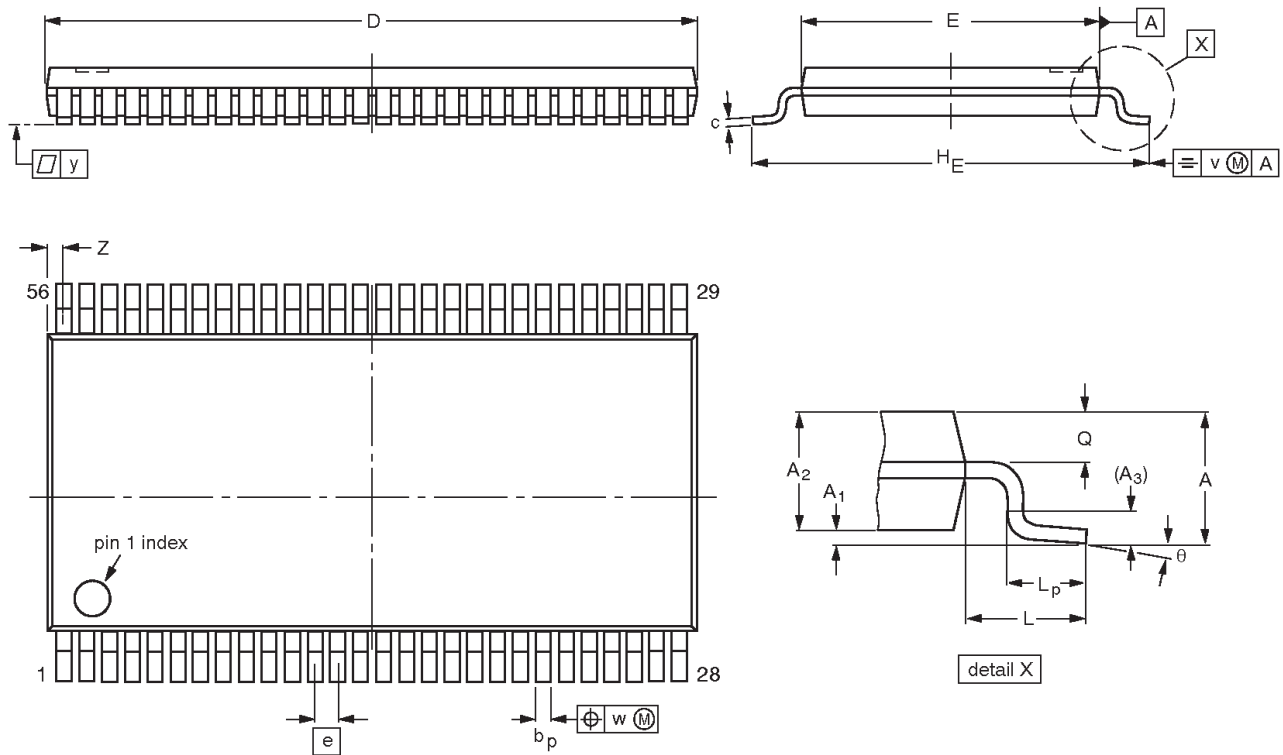
Waveform 6. Load circuitry for switching times

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TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1mm

SOT364-1



DIMENSIONS (mm are the original dimensions).

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	Z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	14.1 13.9	6.2 6.0	0.5	8.3 7.9	1.0	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.5 0.1	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT364-1		MO-153EE				93-02-03 95-02-10

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NOTES

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Data sheet status

Data sheet status	Product status	Definition ^[1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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